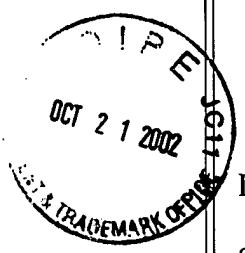


IN THE UNITED STATES PATENT AND TRADEMARK OFFICE



2811  
#7121  
10/24/02  
SEARCHED  
TECHNOLOGY CENTER 2800  
OCT 23 2002  
RECEIVED  
U.S. PATENT AND TRADEMARK OFFICE

In re Appln. Of: MAYUZUMI

Serial No.: 10/036,955 ✓

Filed: December 20, 2001

For: SEMICONDUCTOR DEVICE AND METHOD OF ...

Group: 2811

Examiner: IM, JUNGHWAN M.

DOCKET: NEC 01FN061

Assistant Commissioner of Patents  
Washington, D.C. 20231

**AMENDMENT B**

Dear Sir:

This Amendment is being filed in response to the Official Action mailed  
August 14, 2002.

Please amend the Application as follows:

**IN THE CLAIMS:**

Please amend claims 1, 2, 3, 7, 8, 9, 11, 12 and 13 to read as follows:

1. (Amended) A semiconductor device comprising:  
a semiconductor substrate;  
a gate insulation film formed on said semiconductor substrate;  
a gate electrode formed on said gate insulation film and having a portion increasing  
upward in the length along a gate length direction, said gate electrode further having a visor  
portion;

*A1 Sub B1*

HAYES SOLOWAY P.C.

130 W. CUSHING ST.  
TUCSON, AZ 85701  
TEL. 520.882.7623  
FAX. 520.882.7643

175 CANAL STREET  
MANCHESTER, NH 03101  
TEL. 603.668.1400  
FAX. 603.668.8567